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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











Micro Commercial Components

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20736 Marilla Street Chatsworth

CA 91311

Phone: (818) 701-4933 Fax: (818) 701-4939 MT130CB08T2 MT130CB12T2 MT130CB16T2 MT130CB18T2

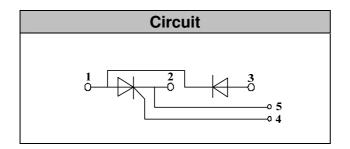
# **Features**

- Lead Free Finish/RoHS Compliant (NOTE 1)("P" Suffix designates RoHS Compliant. See ordering information)
- International standard package
- Heat transfer through aluminum oxide DBC ceramic isolated metal baseplate
- Glass passivated chip
- Simple Mounting

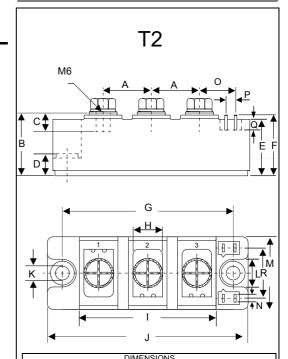
# **Applications**

- Power Converters
- · Lighting Control
- DC Motor Control and Drives
- · Heat and temperature control





# 130 Amp THYRISTOR/DIODE MODULE 800~1800 Volts



		DIME	NSIONS		
	INCHES		ММ		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.894	.917	22.70	23.30	
В	1.169	1.193	29.70	30.30	
C	.343	.366	8.70	9.30	
D	.323	.343	8.20	8.70	
Е	1.051	1.075	26.70	27.30	
F	1.130	1.154	28.70	29.30	
G	.120	.130	79.70	80.30	
Н	.500	.524	12.70	13.30	
	2.501	2.531	63.70	64.30	
J	3.689	3.713	93.70	94.30	
K	.25	56	6.	50	Ø
L	.500	.524	12.70	13.30	
М	1.327	1.350	33.70	34.30	
N	0.0	032X0.11	0.	8X2.8	
0	.677	.700	17.20	17.80	
Р	.185	.209	4.70	5.30	
Q	.185	.209	4.70	5.30	
R	.902	.925	22.90	23.50	



# **Module Type**

TYPE	VRRM/VDRM	Vrsm
MT130CB08T2	800V	900V
MT130CB12T2	1200V	1300V
MT130CB16T2	1600V	1700V
MT130CB18T2	1800V	1900V

### **♦**Diode

**Maximum Ratings** 

Symbol	Item	Conditions	Values	Units
ID	Output Current(D.C.)	Tc=85°C	130	Α
IFSM	Surge forward current	t=10mS Tvj =45℃	4700	Α
i <sup>2</sup> t	Circuit Fusing Consideration		110000	$A^2s$
Visol	Isolation Breakdown Voltage(R.M.S)	a.c.50HZ;r.m.s.;1min	3000	V
Tvj	Operating Junction Temperature		-40 to +125	$^{\circ}\!\mathbb{C}$
Tstg	Storage Temperature		-40 to +125	$^{\circ}\mathbb{C}$
Mt	Mounting Torque	To terminals(M6)	3±15%	Nm
Ms		To heatsink(M6)	5±15%	Nm
Weight	Module (Approximately)		165	g

# **Thermal Characteristics**

Symbol	Item	Conditions	Values	Units
Rth(j-c)	Thermal Impedance, max.	Junction to Case	0.09	°C/W
Rth(c-s)	Thermal Impedance, max.	Case to Heatsink	0.05	°C/W

# **Electrical Characteristics**

Symbol	Symbol Item Co		Values			Units
Symbol	nem	Conditions	Min.	Тур.	Max.	Units
VFM	Forward Voltage Drop, max.	T=25℃ IF =500A			1.80	V
IRRM	Repetitive Peak Reverse Current, max.	Tvj =25°C VRD=VRRM Tvj =125°C VRD=VRRM		≤0.5 ≤9		mA mA



# **◆**Thyristor

# **Maximum Ratings**

Symbol	Item	Conditions	Values	Units
I <sub>TAV</sub>	Average On-State Current	Sine 180°;Tc=85℃	130	Α
I <sub>TSM</sub>	Surge On-State Current	$T_{VJ}$ =45°C t=10ms, sine $T_{VJ}$ =125°C t=10ms, sine	4700 4000	Α
i <sup>2</sup> t	Circuit Fusing Consideration	$T_{VJ}$ =45°C t=10ms, sine $T_{VJ}$ =125°C t=10ms, sine	110000 80000	A2s
Visol	Isolation Breakdown Voltage(R.M.S)	a.c.50HZ;r.m.s.;1min	3000	V
Tvj	Operating Junction Temperature		-40 to +130	$^{\circ}\!\mathbb{C}$
Tstg	Storage Temperature		-40 to +125	$^{\circ}\!\mathbb{C}$
Mt	Mounting Torque	To terminals(M6)	$3\pm15\%$	Nm
Ms		To heatsink(M6)	$5\!\pm\!15\%$	Nm
di/dt	Critical Rate of Rise of On-State Current	$T_{VJ}$ = $T_{VJM}$ , 2/3 $V_{DRM}$ , $I_{G}$ =500mA Tr<0.5us,tp>6us	200	A/us
dv/dt	Critical Rate of Rise of Off-State Voltage, min.	T <sub>J</sub> =T <sub>VJM</sub> ,2/3V <sub>DRM</sub> linear voltage rise	1000	V/us
а	Maximum allowable acceleration		50	m/s <sup>2</sup>

# **Thermal Characteristics**

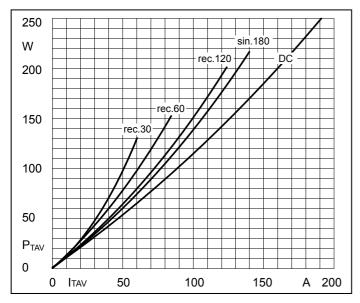
Symbol	Item	Conditions	Values	Units
Rth(j-c)	Thermal Impedance, max.	Junction to Case	0.18	°C/W
Rth(c-s)	Thermal Impedance, max.	Case to Heatsink	0.10	°C/W

# **Electrical Characteristics**

Cymbol	Itam	Conditions	Value	s	Units
Symbol	Item	Conditions			Units
V <sub>TM</sub>	Peak On-State Voltage, max.	T=25℃ I <sub>T</sub> =500A		1.8	V
I <sub>RRM</sub> /I <sub>DRM</sub>	Repetitive Peak Reverse Current, max. / Repetitive Peak Off-State Current, max.	$T_{VJ}=T_{VJM}$ , $V_R=V_{RRM}$ , $V_D=V_{DRM}$		40	mA
V <sub>TO</sub>	On state threshold voltage	For power-loss calculations only (T <sub>VJ</sub> =125°C)		1	V
r <sub>T</sub>	Value of on-state slope resistance. max	$T_{VJ} = T_{VJM}$		1.6	mΩ
$V_{GT}$	Gate Trigger Voltage, max.	$T_{VJ}$ =25 $^{\circ}$ C , $V_{D}$ =6 $V$		3	V
I <sub>GT</sub>	Gate Trigger Current, max.	$T_{VJ}$ =25°C , $V_D$ =6V		150	mA
$V_{\sf GD}$	Non-triggering gate voltage, max.	$T_{VJ}$ =125°C, $V_D$ =2/3 $V_{DRM}$		0.25	V
$I_{GD}$	Non-triggering gate current, max.	$T_{VJ}$ =125°C, $V_D$ =2/3 $V_{DRM}$		10	mA
IL	Latching current, max.	$T_{VJ}$ =25°C , $R_G$ = 33 $\Omega$	300	1000	mA
I <sub>H</sub>	Holding current, max.	T <sub>VJ</sub> =25℃ , V <sub>D</sub> =6V	150	400	mA
tgd	Gate controlled delay time	TVJ=25℃, IG=1A, diG/dt=1A/us	1		us
tq	Circuit commutated turn-off time	$T_{VJ} = T_{VJM}$	100		us



### **Performance Curves**



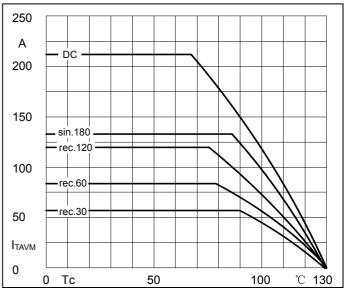
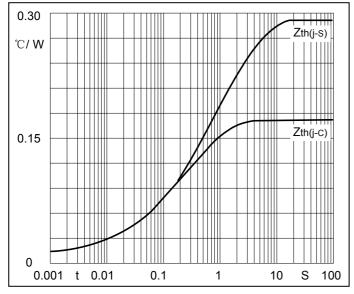


Fig1. Power dissipation

**Fig2.Forward Current Derating Curve** 





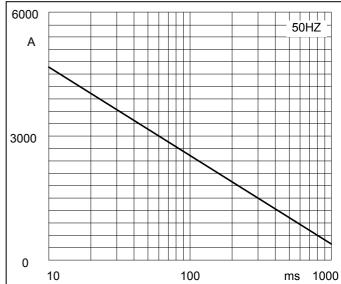


Fig4. Max Non-Repetitive Forward Surge Current



### **Performance Curves**

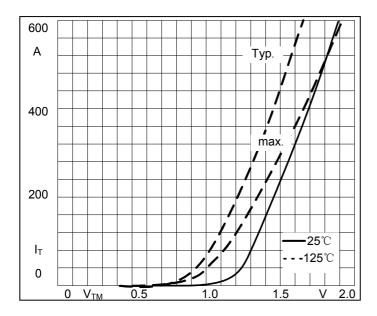


Fig5. Forward Characteristics

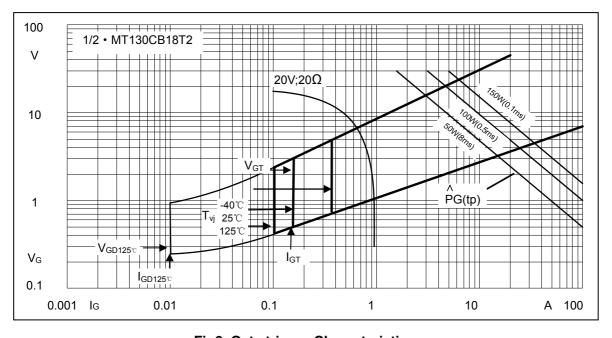


Fig6. Gate trigger Characteristics



## **Ordering Information:**

Device	Packing
Part Number-BP	Bulk: 8PCS/BOX;80PCS/CTN

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